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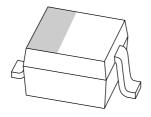
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



PDZ-B seriesVoltage regulator diodes

Product data sheet Supersedes data of 2002 Feb 18 2004 Mar 22



Voltage regulator diodes

PDZ-B series

FEATURES

- Total power dissipation: max. 400 mW
- Small plastic package suitable for surface mounted design
- Wide variety of voltage ranges: nominal 2.4 to 36 V (E24 range)
- Tolerance approximately ±2%.

APPLICATIONS

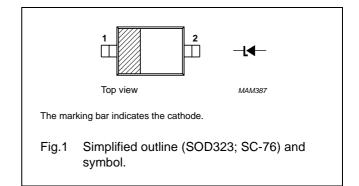
· General voltage regulation.

DESCRIPTION

Low-power general purpose voltage regulator diodes in a small plastic SMD SOD323 (SC-76) package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode



MARKING

TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE
PDZ2.4B	Z0	PDZ5.1B	Z8	PDZ11B	ZG	PDZ24B	ZQ
PDZ2.7B	Z1	PDZ5.6B	Z9	PDZ12B	ZH	PDZ27B	ZR
PDZ3.0B	Z2	PDZ6.2B	ZA	PDZ13B	ZJ	PDZ30B	ZS
PDZ3.3B	Z3	PDZ6.8B	ZB	PDZ15B	ZK	PDZ33B	ZT
PDZ3.6B	Z4	PDZ7.5B	ZC	PDZ16B	ZL	PDZ36B	ZU
PDZ3.9B	Z5	PDZ8.2B	ZD	PDZ18B	ZM		
PDZ4.3B	Z6	PDZ9.1B	ZE	PDZ20B	ZN		
PDZ4.7B	Z7	PDZ10B	ZF	PDZ22B	ZP	_	

ORDERING INFORMATION

TYPE	PACKAGE					
NUMBER	NAME	DESCRIPTION	VERSION			
PDZ2.4B to PDZ36B	_	plastic surface mounted package; 2 leads	SOD323			

Voltage regulator diodes

PDZ-B series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _F	continuous forward current		_	200	mA
I _{ZSM}	non-repetitive peak reverse current	t_p = 100 μ s; square wave; T_{amb} = 25 °C prior to surge	,	see Table 2	2
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1; see Fig.2	_	400	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

Note

1. Device mounted on a printed-circuit board measuring 11 \times 25 \times 1.6 mm.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-s)}$	thermal resistance from junction to soldering point		130	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	340	K/W

Note

1. Device mounted on a printed-circuit board measuring 11 \times 25 \times 1.6 mm.

Voltage regulator diodes

PDZ-B series

CHARACTERISTICS

Table 1 Total series

 $T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	$I_F = 10 \text{ mA}$; see Fig.3	0.9	V
		$I_F = 100 \text{ mA}$; see Fig.3	1.1	V
I _R	reverse current			
	PDZ2.4B	V _R = 1 V	50	μΑ
	PDZ2.7B	V _R = 1 V	20	μΑ
	PDZ3.0B	$V_R = 1 V$	10	μΑ
	PDZ3.3B	V _R = 1 V	5	μΑ
	PDZ3.6B	V _R = 1 V	5	μΑ
	PDZ3.9B	V _R = 1 V	3	μΑ
	PDZ4.3B	V _R = 1 V	3	μΑ
	PDZ4.7B	V _R = 1 V	2	μΑ
	PDZ5.1B	V _R = 1.5 V	2	μΑ
	PDZ5.6B	$V_{R} = 2.5 \text{ V}$	1	μΑ
	PDZ6.2B	$V_R = 3 V$	500	nA
	PDZ6.8B	$V_{R} = 3.5 \text{ V}$	500	nA
	PDZ7.5B	$V_R = 4 V$	500	nA
	PDZ8.2B	$V_R = 5 V$	500	nA
	PDZ9.1B	V _R = 6 V	500	nA
	PDZ10B	$V_R = 7 V$	100	nA
	PDZ11B	V _R = 8 V	100	nA
	PDZ12B	V _R = 9 V	100	nA
	PDZ13B	V _R = 10 V	100	nA
	PDZ15B	V _R = 11 V	50	nA
	PDZ16B	V _R = 12 V	50	nA
	PDZ18B	V _R = 13 V	50	nA
	PDZ20B	V _R = 15 V	50	nA
	PDZ22B	V _R = 17 V	50	nA
	PDZ24B	V _R = 19 V	50	nA
	PDZ27B	V _R = 21 V	50	nA
	PDZ30B	V _R = 23 V	50	nA
	PDZ33B	V _R = 25 V	50	nA
	PDZ36B	V _R = 27 V	50	nA

PDZ-B series

Table 2 Per type

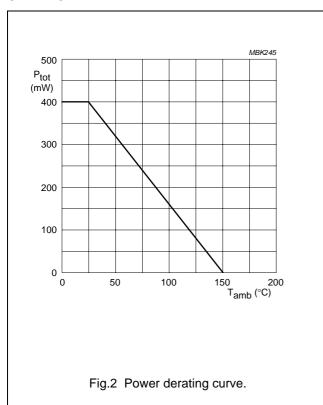
 $T_i = 25$ °C unless otherwise specified.

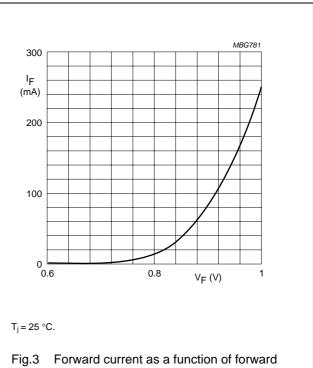
TYPE NUMBER	WORKING VOLTAGE V _Z (V) at I _Z = 5 mA		V _Z (V) DIFFERENTIAL RESISTANCE				TEMP. COEFF. S_Z (mV/K) at $I_Z = 5$ mA (see Figs 4 and 5)	DIODE CAP. C_d (pF) at $f = 1$ MHz; $V_R = 0$	NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} (A) at t_p = 100 μs ; T_{amb} = 25 °C
	MIN.	MAX.	MAX.	at I _Z (mA)	MAX.	at I _Z (mA)	TYP.	MAX.	MAX.
PDZ2.4B	2.43	2.63	1000	0.5	100	5	-1.6	450	8.0
PDZ2.7B	2.69	2.91	1000	0.5	100	5	-2.0	440	8.0
PDZ3.0B	2.85	3.07	1000	0.5	95	5	-2.1	425	8.0
PDZ3.3B	3.32	3.53	1000	0.5	95	5	-2.4	410	8.0
PDZ3.6B	3.60	3.85	500	1.0	90	5	-2.4	390	8.0
PDZ3.9B	3.89	4.16	500	1.0	90	5	-2.5	370	8.0
PDZ4.3B	4.17	4.48	600	1.0	90	5	-2.5	350	8.0
PDZ4.7B	4.55	4.75	600	1.0	90	5	-1.4	325	8.0
PDZ5.1B	4.96	5.20	250	0.5	60	5	0.3	300	5.5
PDZ5.6B	5.48	5.73	100	0.5	50	5	1.9	275	5.5
PDZ6.2B	6.06	6.33	80	0.5	50	5	2.7	250	5.5
PDZ6.8B	6.65	6.93	60	0.5	40	5	3.4	215	5.5
PDZ7.5B	7.28	7.60	60	0.5	10	5	4.0	170	3.5
PDZ8.2B	8.02	8.36	60	0.5	10	5	4.6	150	3.5
PDZ9.1B	8.85	9.23	60	0.5	10	5	5.5	120	3.5
PDZ10B	9.77	10.21	60	0.5	10	5	6.4	110	3.5
PDZ11B	10.78	11.22	60	0.5	10	5	7.4	108	3.0
PDZ12B	11.74	12.24	80	0.5	10	5	8.4	105	3.0
PDZ13B	12.91	13.49	80	0.5	10	5	9.4	103	2.5
PDZ15B	14.34	14.98	80	0.5	15	5	11.4	99	2.0
PDZ16B	15.85	16.51	80	0.5	20	5	12.4	97	1.5
PDZ18B	17.56	18.35	80	0.5	20	5	14.4	93	1.5
PDZ20B	19.52	20.39	100	0.5	20	5	16.4	88	1.5
PDZ22B	21.54	22.47	100	0.5	25	5	18.4	84	1.3
PDZ24B	23.72	24.78	120	0.5	30	5	20.4	80	1.3
PDZ27B	26.19	27.53	150	0.5	40	5	23.4	73	1.0
PDZ30B	29.19	30.69	200	0.5	40	5	26.6	66	1.0
PDZ33B	32.15	33.79	250	0.5	40	5	29.7	60	0.9
PDZ36B	35.07	36.87	300	0.5	60	5	33.0	59	0.8

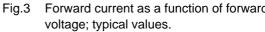
Voltage regulator diodes

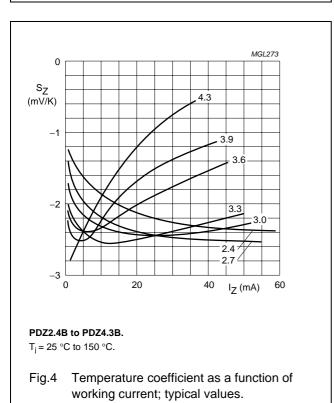
PDZ-B series

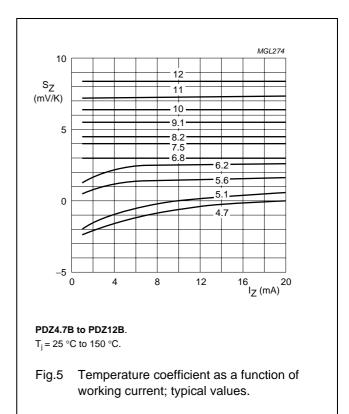
GRAPHICAL DATA











2004 Mar 22 6

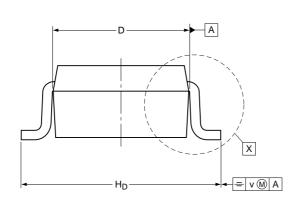
Voltage regulator diodes

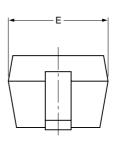
PDZ-B series

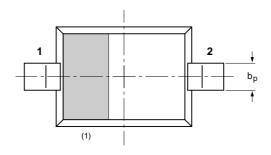
PACKAGE OUTLINE

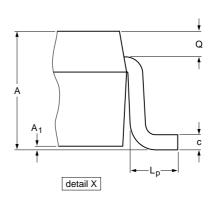
Plastic surface-mounted package; 2 leads

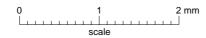
SOD323











DIMENSIONS (mm are the original dimensions)

UN	IT	A	A ₁ max	bp	С	D	E	H _D	Lp	Q	v
mı	m	1.1 0.8	0.05	0.40 0.25	0.25 0.10	1.8 1.6	1.35 1.15	2.7 2.3	0.45 0.15	0.25 0.15	0.2

Note

1. The marking bar indicates the cathode

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOD323			SC-76			03-12-17 06-03-16

Voltage regulator diodes

PDZ-B series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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